





SOP-8

Pin Definition:1. Source 18. Drain 12. Gate 17. Drain 1

3. Source 2 6. Drain 2 4. Gate 2 5. Drain 2

Sale 2 S. Diali

Features

- Advance Trench Process Technology
- High Density Cell Design for Ultra Low On-resistance

Application

- Load Switch
- PA Switch

Ordering Information

Part No.	Package	Packing
TSM4953DCS RLG	SOP-8	2.5Kpcs / 13" Reel

Note: "G" denotes Halogen Free Product.

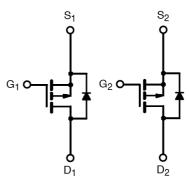
PRODUCT SUMMARY

V _{DS} (V)	R _{DS(on)} (mΩ)	I _D (A)
-30	60 @ V _{GS} = 10V	-4.9
	90 @ V _{GS} = 4.5V	-3.7

30V Dual P-Channel MOSFET

TSM4953D

Block Diagram



Dual P-Channel MOSFET

Absolute Maximum Rating (Ta = 25°C unless otherwise noted)

Parameter		Symbol	Limit	Unit
Drain-Source Voltage		V _{DS}	-30	V
Gate-Source Voltage		V _{GS}	±20	V
Continuous Drain Current, V _{GS} @4.5V.		I _D	-4.9	А
Pulsed Drain Current, V _{GS} @4.5V		I _{DM}	-20	А
Continuous Source Current (Diode Conduction) ^{a,b}		I _S	-2.6	А
Maximum Power Dissipation	Ta = 25°C	P _D	2.5	10/
	Ta = 70°C		1.3	W
Operating Junction Temperature		TJ	+150	°C
Operating Junction and Storage Temperature Range		T _J , T _{STG}	- 55 to +150	°C

Thermal Performance

Parameter	Symbol	Limit	Unit
Junction to Case Thermal Resistance	RƏ _{JC}	40	°C/W
Junction to Ambient Thermal Resistance (PCB mounted)	RƏ _{JA}	62.5	°C/W

Notes:

a. Pulse width limited by the Maximum junction temperature

b. Surface Mounted on FR4 Board, t \leq 5 sec.



Electrical Specifications (Ta = 25°C unless otherwise noted)

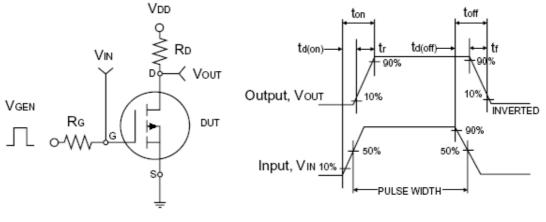
Parameter	Conditions	Symbol	Min	Тур	Max	Unit
Static	·				·	
Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_{D} = -250uA$	BV _{DSS}	-30			V
Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	V _{GS(TH)}	-1.0	-1.5	-3.0	V
Gate Body Leakage	$V_{GS} = \pm 20V, V_{DS} = 0V$	I _{GSS}			±100	nA
Zero Gate Voltage Drain Current	$V_{DS} = -24V, V_{GS} = 0V$	I _{DSS}			-1.0	μA
On-State Drain Current ^a	$V_{DS} = -5V, V_{GS} = -10V$	I _{D(ON)}	-6			А
	$V_{GS} = -10V, I_D = -4.9A$			50	60	mΩ
Drain-Source On-State Resistance ^a	$V_{GS} = -4.5V, I_{D} = -3.7A$	R _{DS(ON)}		75	90	
Forward Transconductance ^a	$V_{DS} = -15V, I_{D} = -4.9A$	g _{fs}		10		S
Diode Forward Voltage	I _S = -1.9A, V _{GS} = 0V	V _{SD}			-1.3	V
Dynamic						
Total Gate Charge		Qg		28		
Gate-Source Charge	$V_{DS} = -15V, I_D = -4.9A,$ $V_{GS} = -10V$	Q _{gs}		3		nC
Gate-Drain Charge		Q _{gd}		7		
Input Capacitance	$V_{DS} = -15V, V_{GS} = 0V,$ f = 1.0MHz	C _{iss}		745		
Output Capacitance		C _{oss}		440		pF
Reverse Transfer Capacitance		C _{rss}		120		
Switching					•	
Turn-On Delay Time	$V_{DD} = -15V, R_{L} = 15\Omega,$ $I_{D} = -1A, V_{GEN} = -10V,$ $R_{G} = 6\Omega$	t _{d(on)}		9		
Turn-On Rise Time		t _r		15		
Turn-Off Delay Time		t _{d(off)}		75		nS
Turn-Off Fall Time		t _f		40		

Notes:

1. pulse test: PW \leq 300µS, duty cycle \leq 2%

2. For DESIGN AID ONLY, not subject to production testing.

3. Switching time is essentially independent of operating temperature.

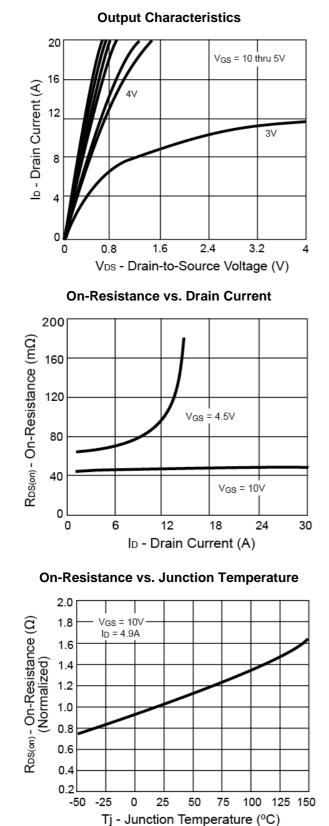


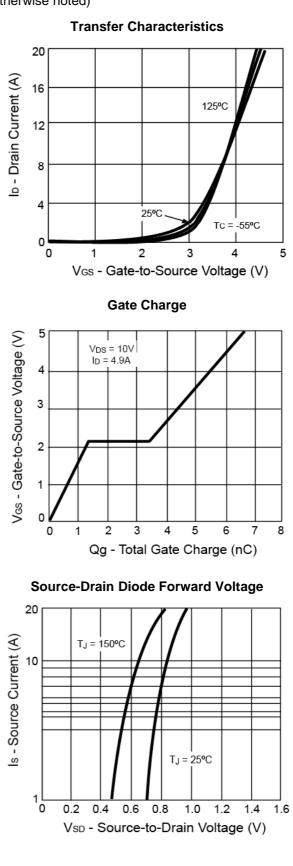
Switching Test Circuit

Switchin Waveforms



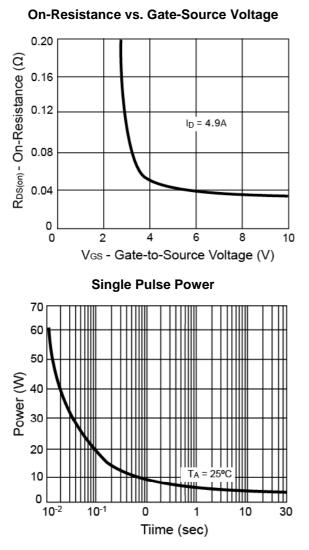
Electrical Characteristics Curve (Ta = 25°C, unless otherwise noted)

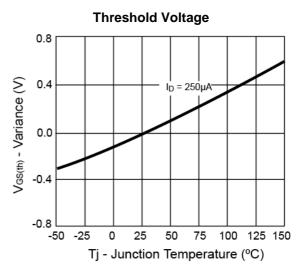




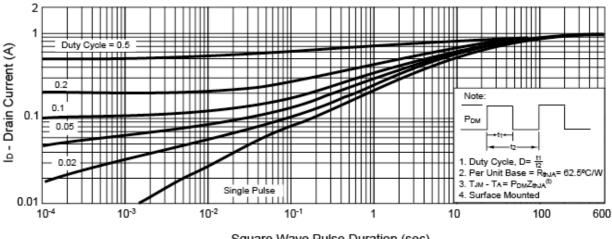


Electrical Characteristics Curve (Ta = 25°C, unless otherwise noted)





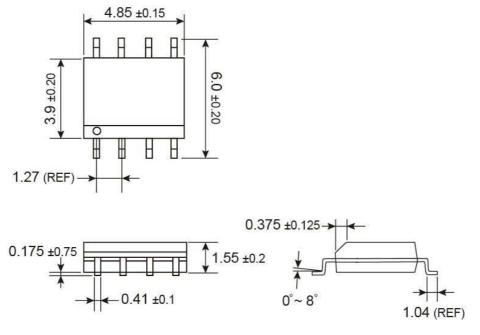
Normalized Thermal Transient Impedance, Junction-to-Ambient



Square Wave Pulse Duration (sec)



SOP-8 Mechanical Drawing



Unit: Millimeters

Marking Diagram

	Y = Year CodeM = Month Code for Halogen Free Product			
TSM4953D	O =Jan P =Feb Q =Ma	ar R =Apr		
	S =May T =Jun U =Jul	V =Aug		
	W =Sep X =Oct Y =No	v Z =Dec		
	L = Lot Code			



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